PROCEEDINGS OF SPIE

Organic and Hybrid Field-Effect Transistors XXI

lain McCulloch Oana D. Jurchescu Editors

22–24 August 2022 San Diego, California, United States

Sponsored and Published by SPIE

Volume 12211

Proceedings of SPIE 0277-786X, V. 12211

SPIE is an international society advancing an interdisciplinary approach to the science and application of light.

Organic and Hybrid Field-Effect Transistors XXI, edited by Iain McCulloch, Oana D. Jurchescu, Proc. of SPIE Vol. 12211, 1221103 ⋅ © 2022 SPIE 0277-786X ⋅ doi: 10.1117/12.2661547

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Please use the following format to cite material from these proceedings: Author(s), "Title of Paper," in *Organic and Hybrid Field-Effect Transistors XXI*, edited by Iain McCulloch, Oana D. Jurchescu, Proc. of SPIE 12211, Seven-digit Article CID Number (DD/MM/YYYY); (DOI URL).

ISSN: 0277-786X

ISSN: 1996-756X (electronic)

ISBN: 9781510654068

ISBN: 9781510654075 (electronic)

Published by

SPIE

P.O. Box 10, Bellingham, Washington 98227-0010 USA Telephone +1 360 676 3290 (Pacific Time)

SPIE.org

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Contents

v Conference Committee

PROCESSING

12211 01 Completely printed flexible carbon nanotube based transistor using poly-vinyl alcohol (PVA) as gate dielectric via aerosol jet printing [12211-14]

POSTER SESSION

Dimensionality of photogenerated charges transport in the organic phototransistor [12211-33]

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